

# 2SC5625

FOR LOW FREQUENCY AMPLIFY APPLICATION  
SILICON NPN EPITAXIAL TYPE

## DESCRIPTION

2SC5625 is a super mini package resin sealed silicon NPN epitaxial transistor. It is designed for low frequency voltage application.

## FEATURE

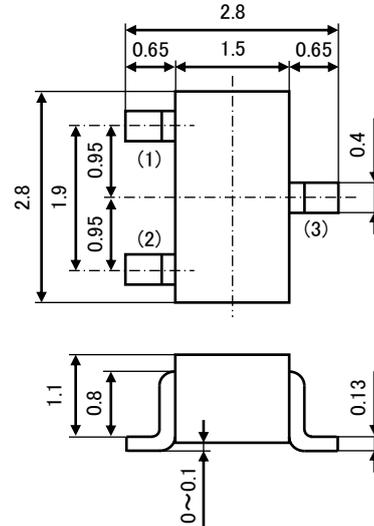
- Super mini package for easy mounting.
- Small collector to emitter saturation voltage.  $V_{CE(sat)}=0.5V$  max

## APPLICATION

DC/DC convertor, High voltage switching

## OUTLINE DRAWING

Unit: mm

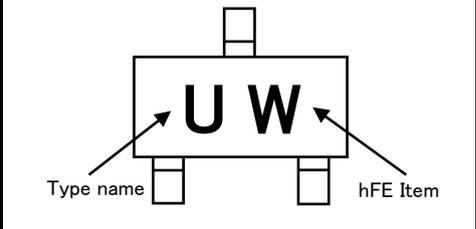


TERMINAL CONNECTOR JEITA: SC-59  
(1) BASE JEDEC: Similar to TO-236  
(2) EMITTER  
(3) COLLECTOR

## MAXIMUM RATINGS (Ta=25°C)

Symbol	Parameter	Ratings	Unit
V <sub>CB0</sub>	Collector to Base voltage	300	V
V <sub>EB0</sub>	Emitter to Base voltage	7	V
V <sub>CE0</sub>	Collector to Emitter voltage	300	V
I <sub>c</sub>	Collector Current	100	mA
P <sub>c</sub>	Collector Dissipation	200	mW
T <sub>j</sub>	Junction Temperature	+150	°C
T <sub>stg</sub>	Storage Temperature	-55~+150	°C

## MARKING



## ELECTRIC CHARACTERISTICS (Ta=25°C)

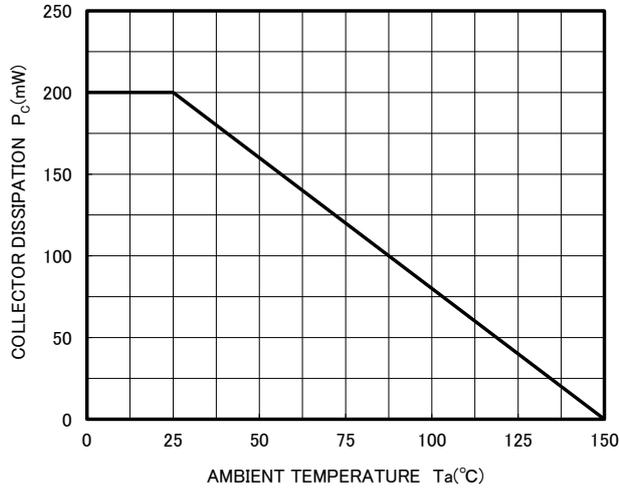
Symbol	Parameter	Test conditions	Limits			Unit
			Min	Typ	Max	
V <sub>(BR)CBO</sub>	C to B breakdown voltage	I <sub>c</sub> =50μA, I <sub>E</sub> =0	300	-	-	V
V <sub>(BR)EBO</sub>	E to B breakdown voltage	I <sub>E</sub> =50μA, I <sub>c</sub> =0	7	-	-	V
V <sub>(BR)CEO</sub>	C to E breakdown voltage	I <sub>c</sub> =1mA, R <sub>BE</sub> =∞	300	-	-	V
I <sub>CB0</sub>	Collector Cutoff Current	V <sub>CB</sub> =300V, I <sub>E</sub> =0	-	-	0.5	μA
I <sub>EB0</sub>	Emitter Cutoff Current	V <sub>EB</sub> =5V, I <sub>c</sub> =0	-	-	0.5	μA
h <sub>FE</sub>	DC Forward Current Gain	V <sub>CE</sub> =10V, I <sub>c</sub> =10mA	60	-	305	-
V <sub>CE(sat)</sub>	C to E Saturation Voltage	I <sub>c</sub> =100mA, I <sub>B</sub> =10mA	-	-	0.5	V
f <sub>t</sub>	Gain Bandwidth Product	V <sub>CE</sub> =6V, I <sub>E</sub> =-10mA	-	40	-	MHz
C <sub>ob</sub>	Collector Output Capacitance	V <sub>CB</sub> =6V, I <sub>E</sub> =0, f=1MHz	-	3.0	-	pF

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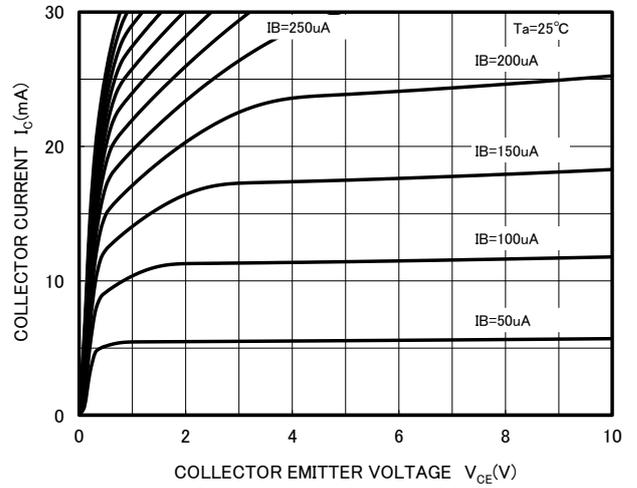
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## TYPICAL CHARACTERISTICS

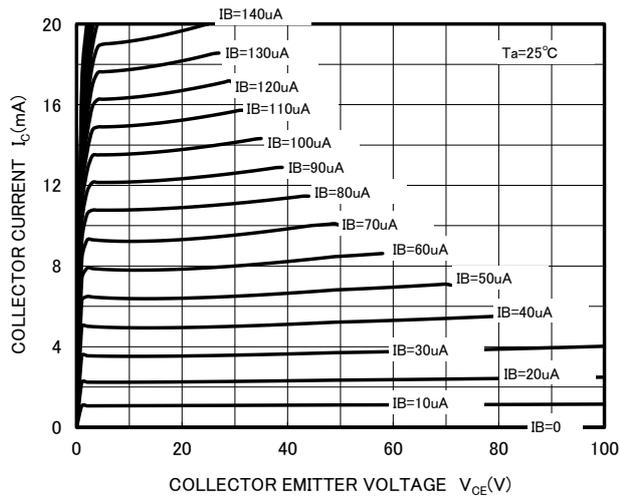
COLLECTOR DISSIPATION VS. AMBIENT TEMPERATURE



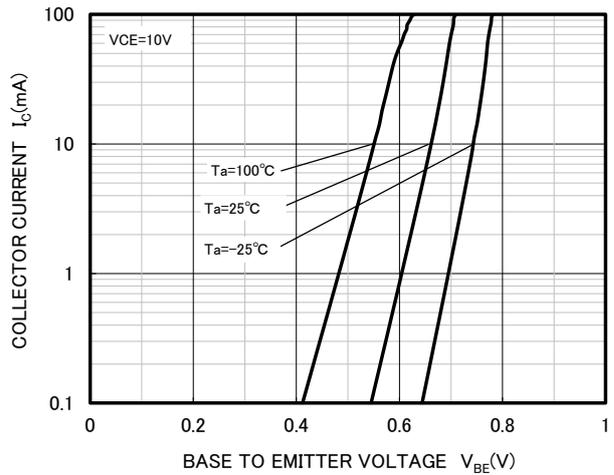
COMMON EMITTER OUTPUT(1)



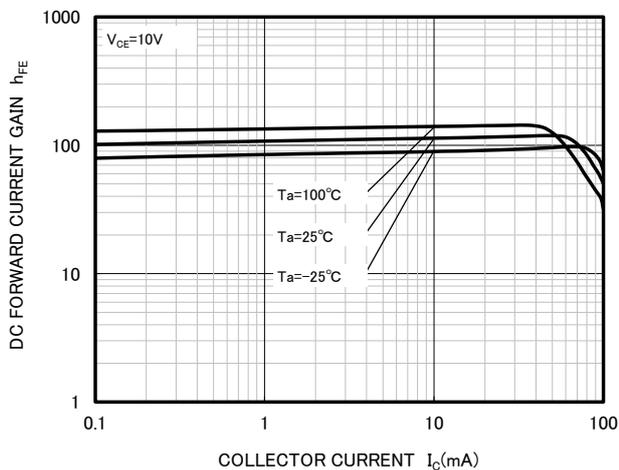
COMMON EMITTER OUTPUT(2)



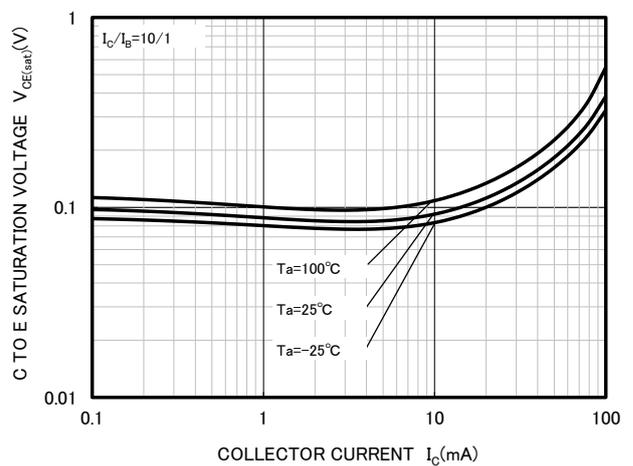
COMMON EMITTER TRANSFER



DC FORWARD CURRENT GAIN VS. COLLECTOR CURRENT



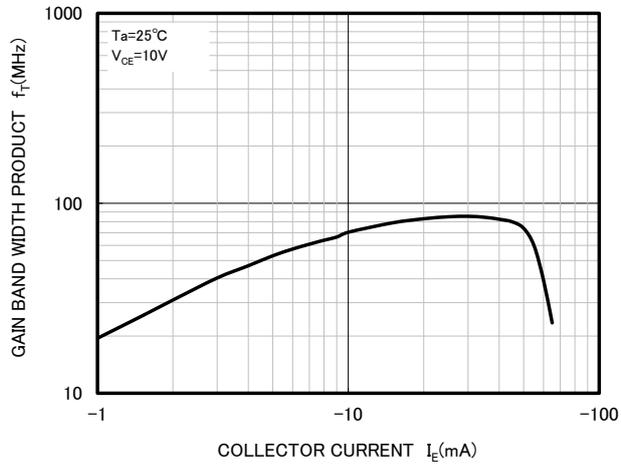
C TO E SATURATION VOLTAGE VS. COLLECTOR CURRENT



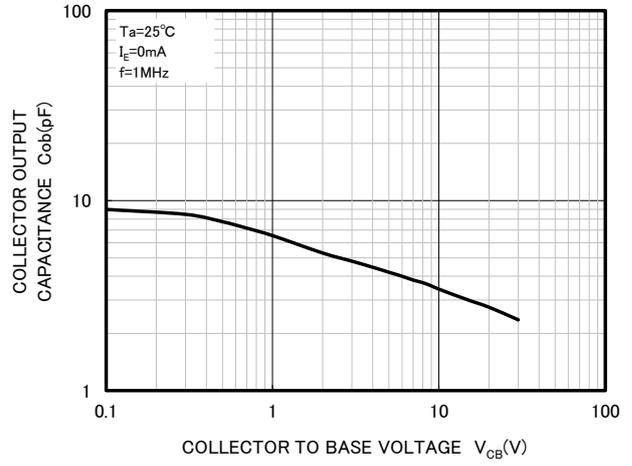
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GAIN BAND WIDTH PRODUCT VS.  
COLLECTOR CURRENT



COLLECTOR OUTPUT CAPACITANCE VS.  
COLLECTOR TO BASE VOLTAGE



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